

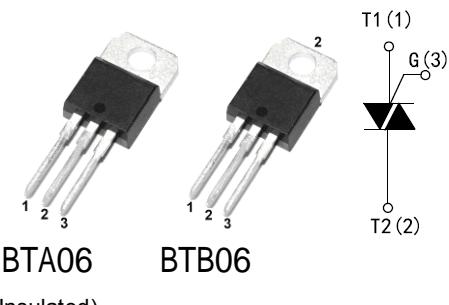
BTA06/BTB06

6A TRIACS

General Description

- Package: TO-220T
- High current density due to double mesa technology, SIPOS and Glass passivation . BTA04/ BTB04 series triacs is Suitable for general purpose AC switching. They can be used as an ON/OFF function in applications such as static relays, heating regulation, induction motor starting circuits... or phase control operation light dimmers, motor speed controllers.
- BTA06/ BTB06 series are 3 Quadrants triacs, They are specially recommended for use on inductive loads.

DRAWING



Absolute Maximum Ratings

| Parameter | | Symbol | Value | Unit |
|--|--|----------------------|--------------|------------------|
| Storage junction temperature range | | T _{stg} | -40 to +150 | °C |
| Operating junction temperature range | | T _j | -40 to + 125 | °C |
| Repetitive Peak OFF-state Voltage | T _j =25°C | V _{DRM} | 800 | V |
| Repetitive Peak Reverse Voltage | T _j =25°C | V _{RRM} | 800 | V |
| Non repetitive surge peak off-state voltage | | V _{DSM} | 800 | V |
| Non repetitive peak reverse voltage | T _p =10ms, T _j =25°C | V _{RSM} | 800 | V |
| RMS on-state current(full sine wave) | T _C =107°C | I _T (RMS) | 6 | A |
| Non repetitive surge peak on-state current(full cycle,T _j =25°C) | f=60Hz,t=16.7ms | ITSM | 65 | A |
| | f=50Hz,t=20ms | | 60 | |
| I ² t Value for fusing | T _p =10ms | I ² t | 3.1 | A ² s |
| Critical rate of rise of on-state current I _G =2*I _{GT} ,t _r ≤100ns,f=120Hz,T _j =125°C | I - II - III IV | dI/dt | 50 20 | A/us |
| Peak gate current(tp=20us,T _j =125°C) | | I _{GM} | 2 | A |
| Peak gate power dissipation(tp=20us,T _j =125°C) | | P _{GM} | 5 | W |
| Average gate power dissipation(T _j =125°C) | | P _{G(AV)} | 0.5 | W |

Electrical Characteristics ($T_j=25^\circ\text{C}$,unless otherwise specified)

| Symbol | Test Condition | Quadrant | | Limit | | | | Unit |
|---------------|---|-----------------|-----|--------------|----------|----------|----------|-------------|
| | | | | D | E | F | G | |
| I_{GT} | $V_D=12\text{V}, R_L=33\Omega$ | I - II - III IV | MAX | 5 | 10 | 25 | 50 | mA |
| V_{GT} | | | | 10 | 25 | 70 | 100 | |
| V_{GD} | $V_D=V_{DRM}$ $R_L=3.3\text{K}\Omega$ $T_j=125^\circ\text{C}$ | ALL | MIN | 0.2 | | | | V |
| I_L | $I_G=1.2I_{GT}$ | I - III - IV | MAX | 15 | 30 | 40 | 60 | mA |
| | | II | MAX | 20 | 40 | 60 | 90 | mA |
| I_H | $I_T=100\text{mA}$ | | MAX | 10 | 25 | 30 | 60 | mA |
| Dv/dt | $VD=67\%V_{DRM}$ gate open $TJ=125^\circ\text{C}$ | | MIN | 5 | 10 | 50 | 200 | V/us |
| $(Dv/dt)c$ | $(dl/dt)c=1.1\text{A/ms}$ $Tj=125^\circ\text{C}$ | | MIN | 1 | 2 | 5 | 10 | V/us |

Static Characteristics

| Symbol | Parameter | Value | Unit |
|---------------|----------------------|--------------|-------------|
| $R_{th}(J-C)$ | Junction to case(AC) | 3.0 | °C/W |

Thermal Resistances

| Symbol | Parameter | Value(MAX) | Unit |
|---------------|----------------------------------|-------------------------|-------------|
| V_{TM} | $ITM=5\text{A}, tp=380\text{us}$ | $T_j=25^\circ\text{C}$ | 1.7 |
| I_{DRM} | $VD=V_{DRM}$ $VR=V_{RRM}$ | $T_j=25^\circ\text{C}$ | 5 |
| I_{RRM} | | $T_j=125^\circ\text{C}$ | 1 |